NSN 5961-00-915-3405

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-915-3405 **Inclosure Material:** Metal **Overall Length:** 1.204 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-64 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.430 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 4.70 amperes forward current, total rms nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 159.0 degrees celsius case **Special Features:** Internal junction configuration arrangement pnpnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0